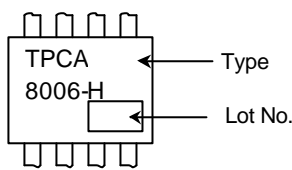


Thermal Characteristics

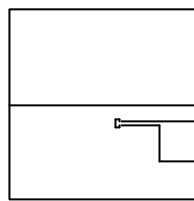
Characteristics	Symbol	Max	Unit
Thermal resistance, channel to case ($T_c=25$)	$R_{th (ch-c)}$	2.78	$^{\circ}C/W$
Thermal resistance, channel to ambient ($t = 10$ s) (Note 2a)	$R_{th (ch-a)}$	44.6	$^{\circ}C/W$
Thermal resistance, channel to ambient ($t = 10$ s) (Note 2b)	$R_{th (ch-a)}$	78.1	$^{\circ}C/W$

Marking (Note 5)

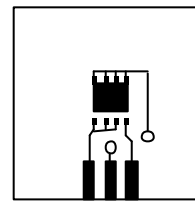


Note 1: Please use devices on condition that the channel temperature is below 150°C.

Note 2: (a) Device mounted on a glass-epoxy board (a) (b) Device mounted on a glass-epoxy board (b)



(a)

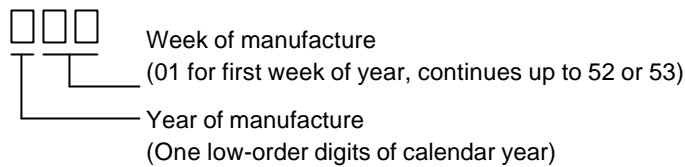


(b)

Note 3: $V_{DD} = 50$ V , $T_{ch} = 25^{\circ}C$ (initial) , $L = 0.8$ mH , $R_G = 25 \Omega$, $I_{AR} = 18$ A

Note 4: Repetitive rating: pulse width limited by max channel temperature

Note 5: * Weekly code: (Three digits)



Electrical Characteristics (Ta = 25°C)

Characteristics		Symbol	Test Condition	Min	Typ.	Max	Unit
Gate leakage current		I_{GSS}	$V_{GS} = \pm 20\text{ V}, V_{DS} = 0\text{ V}$	—	—	± 100	nA
Drain cut-OFF current		I_{DSS}	$V_{DS} = 100\text{ V}, V_{GS} = 0\text{ V}$	—	—	100	μA
Drain-source breakdown voltage		$V_{(BR)DSS}$	$I_D = 10\text{ mA}, V_{GS} = 0\text{ V}$	100	—	—	V
Gate threshold voltage		V_{th}	$V_{DS} = 10\text{ V}, I_D = 1\text{ mA}$	3.0	—	5.0	V
Drain-source ON resistance		$R_{DS(ON)}$	$V_{GS} = 10\text{ V}, I_D = 9\text{ A}$	—	41	67	$\text{m}\Omega$
Forward transfer admittance		$ Y_{fs} $	$V_{DS} = 10\text{ V}, I_D = 9\text{ A}$	7.5	15	—	S
Input capacitance		C_{iss}	$V_{DS} = 10\text{ V}, V_{GS} = 0\text{ V}, f = 1\text{ MHz}$	—	780	—	pF
Reverse transfer capacitance		C_{rss}		—	17	—	
Output capacitance		C_{oss}		—	390	—	
Switching time	Rise time	t_r	<p>$V_{GS} = 10\text{ V}$ 0 V $I_D = 9\text{ A}$ V_{OUT} 4.7Ω $R_L = 5.6\Omega$ $V_{DD} = 50\text{ V}$ Duty $\leq 1\%$, $t_w = 10\ \mu\text{s}$</p>	—	(3)	—	ns
	Turn-ON time	t_{on}		—	(13)	—	
	Fall time	t_f		—	2	—	
	Turn-OFF time	t_{off}		—	13	—	
Total gate charge (gate-source plus gate-drain)		Q_g	$V_{DD} = 80\text{ V}, V_{GS} = 10\text{ V}, I_D = 18\text{ A}$	—	12	—	nC
Gate-source charge 1		Q_{gs1}		—	5.6	—	
Gate-drain ("miller") charge		Q_{gd}		—	4.0	—	
Gate switch charge		Q_{sw}		—	6.9	—	

Source-Drain Ratings and Characteristics (Ta = 25°C)

Characteristics		Symbol	Test Condition	Min	Typ.	Max	Unit
Drain reverse current	Pulse	I_{DRP}	—	—	—	36	A
Forward voltage (diode)		V_{DSF}	$I_{DR} = 18\text{ A}, V_{GS} = 0\text{ V}$	—	—	-1.7	V

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